

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- *Low Forward Voltage.
- *Low Switching noise.
- *High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- *175℃ Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- *Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

Characteristic	Symbol	MBRF2065C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	65	V
RMS Reverse Voltage	V _{R(RMS)}	45	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C =100 $^{\circ}$ C	I _{F(AV)}	10 20	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	150	А
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175	$^{\circ}$

THERMAL RESISTANCES

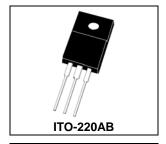
Typical Thermal Resistance junction to case (per diode)	R _{θ j-c}	3.2	°C/w

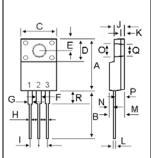
ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	MBRF2065C	Unit
$\label{eq:maximum_loss} \begin{array}{ll} \text{Maximum Instantaneous Forward Voltage} \\ \text{(I}_F = 10 \text{ Amp T}_C = 25^{\circ}\text{C)} & \text{(per diode)} \\ \text{(I}_F = 10 \text{ Amp T}_C = 125^{\circ}\text{C)} \end{array}$	V _F	0.75 0.68	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	I _R	0.01 20	mA

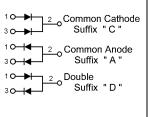
SCHOTTKY BARRIER RECTIFIERS

20 AMPERES 65 VOLTS

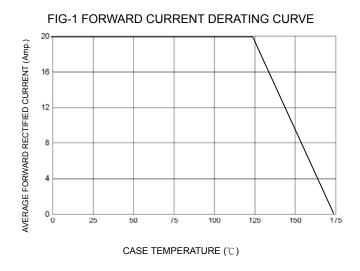


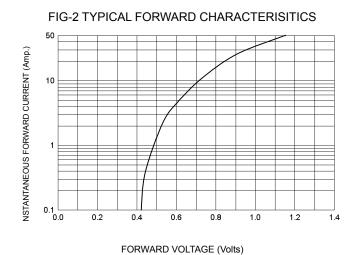


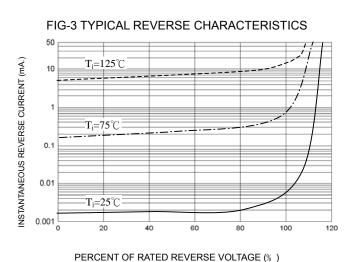
	MILLIMETERS		
DIM	MIN	MAX	
_			
Α	14.90	15.15	
В	13.35	13.55	
С	10.00	10.10	
D	6.55	6.65	
E	2.65	2.75	
F	1.55	1.65	
G	1.15	1.25	
Н	0.55	0.65	
- 1	2.50	2.60	
J	3.00	3.20	
K	1.10	1.20	
L	0.55	0.65	
M	4.40	4.60	
N	1.15	1.25	
0	3.35	3.45	
Р	2.65	2.75	
Q	3.15	3.25	
R	3.60	3.80	

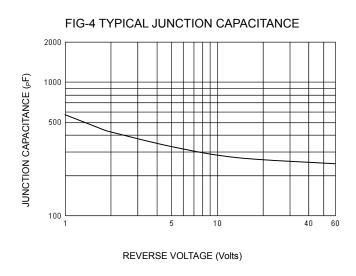


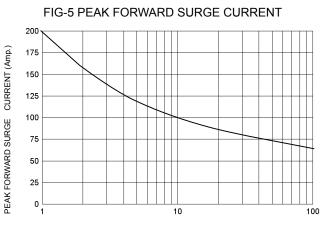
MBRF2065C













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